

Part: T106D1

Series: Teccor® Sensitive SCR Devices

Technology:SCRs

PARAMETERS		
Package Type	Pkg Type	Radial Leaded
Mount Method	Mount	Through Hole
Critical Rate-of-rise of On-state Current	di/dt (A/Âμs)	50
Critical rate-of-rise of applied forward voltage	dv/dt @ 100°C V/Âμs	8
Peak off-state forward and reverse current	I _{DRM} &I _{RRM} @ 100°C (mA)	100.0000
Peak off-state forward and reverse current	I _{DRM} &I _{RRM} @ 125°C (mA)	0.0000
Peak off-state forward and reverse current	I _{DRM} &I _{RRM} @ 25°C (mA)	2.0000
Peak Gate Current	I _{GM} (A)	1
Average on-state current	I _{T(AV)} MAX (A)	2.5000
RMS Surge (Non-repetitive) On-state Fusing Current	I ² t (A ² Sec)	1
Average Gate Power Dissipation	P _{G(AV)} (W)	0.1000
Peak Gate Power Dissipation	P _{GM} (W)	1
Package Size/Form Factor	size	TO-202
Gate-controlled Turn-on time	T _{GT} (Âμs)	4
Circuit commutated turn-off time	T _Q (Âμs)	50
Peak Reverse Gate Voltage	V _{GRM} MIN (V)	6
Gate Trigger Voltage	V _{GT} @ 110°C min (V)	0.2000
Gate Trigger Voltage	V _{GT} @ 125°C min (V)	0.0000
Peak on-state Gate Trigger Voltage	V _{GTM} (V)	1.0000
Gate Trigger Voltage	Vgt @ 25°C max (V)	0.8000
Maximum on-state current	I _{T(RMS)} max (A)	4.0
Repetitive Peak Off-state Forward and Reverse Voltage	V _{DRM} & V _{RRM} (V)	400
Gate Trigger Current	I _{GT} MAX (mA)	0.00
Gate Trigger Current	I _{GT} MAX (ÂμΑ)	0
Gate Trigger Current	I _{GT} MIN (mA)	0.00
Gate Trigger Current	I _{GT} MAX (ÂμΑ)	200
Holding Current	I _H MAX (mA)	5
Surge (Non-repetitive) On-state current	I _{TSM} @ 60Hz (A)	20
Surge (Non-repetitive) On-state current	I _{TSM} @ 50Hz (A)	16
Peak on-state voltage at maximum rated RMS current	V _{TM} MAX (V)	2.2000
Critical rate-of-rise of applied forward voltage	dv/dt @ 125°C V/Âμs	0

